Effects of Metal–Organic Chemical Vapour Deposition grown seed layer on the fabrication of well aligned ZnO nanorods by Chemical Bath Deposition

Maria Elena Fragalà a,⁎, Yana Aleeva b, Graziella Malandrino a

a Dipartimento di Scienze Chimiche Università di Catania and INSTM UdR Catania, Viale Andrea Doria,6, Catania, Italy
b Scuola Superiore Università di Catania, Dipartimento di Scienze Chimiche Viale Andrea Doria,6, Catania, Italy

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A B S T R A C T

Well aligned, long and uniform ZnO nanorods have been reproducibly fabricated adopting a two-steps Metal-Organic Chemical Vapour Deposition (MOCVD) and Chemical Bath Deposition (CBD) fabrication approaches. Thin (~100 nm) ZnO buffer layers have been seeded on silicon substrates by MOCVD and ZnO layers have been subsequently grown, in form of well textured nanorods, using CBD. It has been found that the structure and thickness of the seed layer strongly influence the final morphology and the crystal texturing of ZnO nanorods as well as the CBD growth rate. There is, in addition, a strong correlation between morphologies of CBD grown ZnO nanorods and those of the seed layer underneath. Thus, nanorods deposited over low temperature MOCVD buffer layers are less homogeneous in lateral dimensions and poorly vertically oriented. On the contrary, higher temperature nano-dimensional ZnO seeds favour the CBD growth of almost monodimensional homologue nanorods, with an adequate control of the lateral transport of matter. The nanorod aspect ratio values decrease upon increasing the deposition temperatures of the seed layers. Moreover, the nanorods length can be tailored either by adjusting the CBD growth time or by changing concentration of the N,N,N′-tetramethylhylenediamine ligand used in the CBD process. In particular, at high concentrations, the CBD process is faster with a greater global aspect ratio in agreement with a preferential one-dimensional growth of the ZnO nanostructures. Finally, these ZnO nanorod arrays possess good optical quality in accordance to the photoluminescence properties.

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1. Introduction

ZnO nanostructures are catalysing considerable scientific attention for application spanning from energy storage and conversion devices to biomedical sensors [1]. In particular, nanorods, nanowires and, more generally, one-dimensional (1-D) nanostructures possess unique properties and a large surface to volume ratio that offer a great potential for advanced and highly efficient nano-devices [1,2].

A large variety of techniques has been proposed to fabricate vertically aligned ZnO nanostructures. Nevertheless, the present technological demand presses toward flexible, low cost, easily scalable and reproducible approaches and solution methods involving liquid phase deposition strategy become appealing for their simple apparatus and low temperature requirements. These, however, still lack of suited uniformity control, especially on the large scale. Lately, homoepitaxial routes have proven well suited for ZnO nanoarrays formation using homologous seed layers to promote the uniform growth of oriented nanorods from aqueous solutions. In fact, despite hydrothermal procedures are capable of ZnO growth without seed layers, most of the literature, related to solution approaches, has been focused on the use of homoepitaxial ZnO seed layer, such as crystals or thin films [4–7]. The presence of nucleation sites lowers the energy barrier in Chemical Bath Deposition (CBD), improves the aspect ratio of the obtained nanorods [5,6] and favours a better uniformity [7].

Seed layers deposited over various substrates by drop casting, sputtering or spin coating of Zn sols onto the substrates with a following post-annealing, favour ZnO crystal growth. Similarly, the decomposition of zinc acetate has been proposed to produce nucleation sites for ZnO nanowires [8,9]. Moreover, it has been shown that pre-coating of glass and silicon substrates via sol-gel/spin coating [9–13], annealing of either Radio Frequency (RF) sputtered [14] or Metal-Organic Chemical Vapour Deposition (MOCVD) [15–17] deposited seed layers enhances texturing and crystallinity and is crucial for the formation of aligned ZnO nanowire/nanorod overlayers with improved properties.

The present paper presents a systematic study of effects of morphologies of ZnO seed layers, deposited via MOCVD on Si substrates in a wide temperature ranges (300 °C–600 °C) and deposition times (10 min–60 min), on the properties of ZnO nanorods fabricated using a following CBD process.

We will demonstrate that thickness uniformity, crystallinity and morphology of the ZnO seed layer can be easily and accurately
controlled in a simple MOCVD process to form tunable templates for growing ZnO nanorods from solutions. An accurate control of orientation, morphology, growth density, diameter distribution and crystallinity of ZnO nanoarrays has been obtained with both a good c-axis texturing and a high crystal quality in accordance with a strong emission in the UV region.

2. Experimental details

The deposition of ZnO buffer layer on silicon substrates has been performed in a hot wall tubular reactor, using a diamine (N,N,N′,N′-tetramethylethylenediamine) (TMEDA) adduct of Zinc(II)bis(2-thienyl-trifluoroacetone) [herein Zn(tta)₂•tmdea] [18]. Silicon substrates have been etched in HF for 60 s in order to remove the surface native oxide, washed with water and blown with nitrogen. The substrate temperature has been varied in the 300 °C–600 °C range and deposition times investigated in the 10–60 min range. Ar (250 sccm) and O₂ (250 sccm) have been used as carrier and reactive gas respectively.

The precursor solutions used for CBD growth have been prepared by mixing Zn(CH₃COO)₂•2H₂O with TMEDA water solutions whilst keeping a 1:1 constant volume ratio [19]. All chemicals were of analytical reagent grade and used without further purification. Experiments focused on effect of concentration, were performed by keeping constant the volume ratio of the two solutions for any concentrations studied. The CBD growth has been carried out at 70 °C by dipping the pre-treated substrates in a glass beaker for fixed time periods.

The morphology and size of ZnO nanorods have been studied by Field Emission Scanning Electron Microscopy (FE-SEM) using a ZEISS VP 55 microscope. θ–2θ X-Ray Diffraction (XRD) analyses have been made using a Bruker-AXS D5005 0–0 X-ray diffractometer with Cu Kα radiation operating at 40 kV and 30 mA. Atomic Force Microscopy (AFM) images have been obtained in contact mode in air with an NT-MDT instrument. The root mean-square roughness determined by AFM has been calculated from (2×2) μm² area.

Room temperature photoluminescence (PL) measurements have been performed using a 325 nm He-Cd laser with a 2.5 W/cm² incident power density. The PL spectra have been recorded with a monochromator fitted with 1800 grooves/mm grating and a photomultiplier tube.

![Fig. 1. SEM images of ZnO buffer layers deposited on Si substrates by MOCVD at 300 °C (a), 400 °C (b), 500 °C (c) and 600 °C (d).](image1)

![Fig. 2. AFM images of ZnO buffer layers deposited on Si substrates by MOCVD at 300 °C (a), 400 °C (b), 500 °C (c) and 600 °C (d).](image2)

![Fig. 3. Root Mean Square (RMS) roughness of ZnO buffer layers vs MOCVD deposition temperature.](image3)
3. Results

3.1. ZnO buffer layer MOCVD deposition

It is well known that CBD growth of ZnO nanorods overlayers requires uniform and well oriented seeds and, therefore, involves stringent requirements to favour one-dimensional monocystal growth without lateral transport of matter [20–22]. Several seeding strategies including sol–gel spin coating or dip-coating (followed by high temperature treatments) and physical methods [14,20] have been used. By contrast, Chemical Vapour Deposition, has been poorly investigated despite it represents a low cost, viable, easily and tuneable, conformal route. Some systematic studies have investigated effects of thermal annealing treatments of MOCVD ZnO buffer layers in the perspective of improving the properties of the subsequently deposited CBD ZnO main layer [16,17]. Nevertheless, systematic effects upon varying MOCVD parameters have not been scrutinised.

In this general scenario we have investigated ZnO buffer layers deposited in a low pressure hot-wall MOCVD reactor within a
300 °C–600 °C temperature range using Zn(tta)_2•tmdea as Zn precursor. Although deposition temperature represents the most critical parameter of any CVD process, both the precursor evaporation temperature and the O2 reacting gas partial pressure, have been expedient to tailor structure, morphology and properties of growing seed films. Preliminary experiments [23] have clearly demonstrated that best clean and pure ZnO films require setting of the evaporation source temperature at 170 °C and of the O2 reacting gas at 250 sccm.

Deposition temperatures affect the morphologies and crystal structures of ZnO buffer layers. SEM analysis provides evidence (Fig. 1a) that ZnO growth proceeds through an island growth mode. At low temperature (300 °C) a discontinuous film structure, characterised by hexagonal flakes, is well evident. As the temperature increases, in particular in the 400 °C–600 °C range, the films become continuous due to coalescence of islands and the granular structure changes from smaller (Fig. 1b) to larger and more geometrically defined grains (Fig. 1c and d). The inferred thickness ranges from ~50 nm for the samples deposited at 400 °C to ~150 nm for those deposited at 600 °C. The thickness of samples deposited at 300 °C can be hardly detected due to the flaky nature of the layer.

The AFM analyses (Fig. 2) are closely tuned to SEM morphologies. There is, therefore, evidence that 300 °C represents a threshold temperature between two different MOCVD growth modes. In fact, disordered flakes are associated at this temperature with an island growth involving a partially covered substrate and, hence a high surface root mean square (RMS) roughness (~12 nm). Above this threshold, a continuous layer becomes predominant and the smoother morphology (RMS ~2–4 nm) appears controlled by the deposition temperature with greater grains and related RMS values increasing parallel to the temperature evolution (Fig. 3).

This behaviour can be related to better quality films upon increasing the temperature and, hence, the mobility of adatoms over the substrate. Under low temperature/mobility regimes, any full crystallisation is precluded in accordance with the slightly discernible XRD patterns of films deposited at 300 °C and 400 °C (Fig. 4). Note, however, that the

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<th>[TMEDA] (mM)</th>
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**Table 1** Dimensions and growth rates of ZnO nanorods vs TMEDA concentration.
negligible films thickness could be also considered to account for the poor XRD signal.

Upon increasing the temperature, a high mobility is favoured and adatoms arrange in well suited positions for crystal growth. Thus, at 500 °C the 002 peak ($2\theta = 34.40^\circ$) becomes narrow (0.3°). The peak further shifts to $2\theta = 34.50^\circ$ at 600 °C, with an even narrow FWHM (0.25°) [15,24].

3.2. ZnO nanorods CBD deposition

The present prototypical seeded films have been subjected to a 2 h CBD process. Thus, equal volumes of equimolar water solution of Zn (CH$_3$COO)$_2$$\cdot$2H$_2$O and TMEDA have been used as precursors, as described elsewhere [19]. The diamine based ligands are often used in CBD due to the dual ability to complex zinc cations (Zn$^{2+}$) [25] and undergo basic hydrolysis. The hydrolytic equilibria of related complexes control the overall CBD growth by a gradual release of Zn$^{2+}$ and OH$^-$ reactants. At 70 °C the dissociation equilibrium of [Zn(TMEDA)$_n$]$^{2+}$ is perturbed and the amino-ligand undergoes basic hydrolysis [19,25]

\[
\frac{[\text{Zn(TMEDA)}_n]^{2+}}{\text{Zn}^2+ + n\text{TMEDA}}
\]

1

\[
2\text{TMEDA} + 2\text{H}_2\text{O} \rightleftharpoons 2\text{TMEDA}^- - \text{H}^+ + 2\text{OH}^-
\]

2

\[
\text{Zn}^2+ + 2\text{OH}^- \rightarrow \text{Zn(OH)}_2 \downarrow \rightarrow \text{ZnO} \downarrow + \text{H}_2\text{O}
\]

3

The growing ZnO nanostructures show a strong correlation between their morphologies and those of the seed layer underneath. It has been discussed in the previous section that MOCVD deposition at 300 °C produces a “flake-like” ZnO buffer layer with an island morphology, not uniformly covering the silicon substrates. The related ZnO nanorods grown by CBD (Fig. 5a) are, thus, slanted and geometrically not well defined. SEM cross section images (Fig. 5b) estimate a mean diameter of ~100 nm. The seed layer is slightly visible in the cross section, due to the flaky nature and thickness discontinuity. The overall stack length is ~400 nm. On passing to ZnO buffer layers deposited at 400 °C, the related ZnO nanorods have the expected hexagonal shape. The nanorods, moreover, possess a more homogeneous distribution of dimensions with an average diameter of ~200 nm and a length of ~400 nm (Fig. 5c and d). The seed layer is well discernible in the cross section with a thickness of about 60 nm (overall stack length ~460 nm). Despite the dense buffer layer, the CBD process still results in poorly vertically oriented ZnO nanorod arrays. This observation matches well with the low crystallinity of the buffer layer, in accordance with the XRD analysis.

By increasing the deposition temperature (500 °C), buffer layers acquire a columnar shape with a greater thickness (~110 nm) and crystallinity. As a consequence, the related CBD ZnO nanorods (Fig. 5e and f) appear more vertically oriented, thinner (mean diameter ~100 nm) and somewhat shorter (~260 nm). In addition, due to the reduced diameter, the mean surface density (number of nanorods/surface unit) is dramatically increased and a dense ZnO nanorods array is formed after CBD (overall stack length of ~370 nm).

Finally, there is evidence that at the highest deposition temperature (600 °C) the CBD process replicate a ZnO overlayer over the primary seeds of ZnO nanorods (~150 nm) (Fig. 5g and h). The almost perfect matching of diameters (~100 nm) results in final CBD grown ZnO nanorods of about ~180 nm length (overall stack length ~330 nm).

It is worth noting that more structured seed layers results in a CBD growth of shorter and thinner (~100 nm) ZnO nanorods as the consequence of comparable mass transport (under comparable bath
concentrations and growth times) over a remarkably increased number of active sites associated to greater surface roughness. Similar arguments can be invoked to understand the evolution of nanorods density upon increasing the MOCVD deposition temperatures of the ZnO seed layers which morphologies evolve from a granular structure to nanorods. This trend, conversely, increases both the related surfaces-to-volume ratio and the numbers of active centres responsible for the heterogeneous nucleation at the interface with the CBD solution. The final consequences are thinner nanorods and more dense structures.

Interesting enough, XRD patterns (Fig. 6) provide evidence of the influence of the crystallographic nature of underlying layers on c-axis texturing of CBD nanostructures upon increasing the MOCVD deposition temperature. In particular, both, the better orientation and crystallisation of the seed layer, favour a higher 002 texturing of CBD ZnO nanorods.

The length of neo formations can be modulated by prolonged CBD treatments. Thus, after 6 h ZnO CBD growth, a buffer deposited at 500 °C, for 60 min (thickness ~110 nm; Fig. 5e and f) produces 750 nm long nanorods (vide infra), whilst after 8 h the length increases up to 1 μm (not shown).

Moreover, a strong correlation has been presently found between the seed layer thickness and the CBD growth rate. Thus, ZnO buffer layers deposited by MOCVD at 500 °C for 30 min (Fig. 7a and b) and 10 min (Fig. 7c and d) have been subjected to 6 h CBD growth and the length of the obtained ZnO nanorods has been compared to that obtained on the buffer layer deposited at the same temperature, for 1 h (Fig. 7e and f). It has been observed that reduction of the MOCVD deposition time (30 min) results in a ~70 nm thick seed layer with an overall length of ZnO nanorods increased to 850 nm (vs 750 nm obtained on thicker seed layer deposited for 1 h, Fig. 7e and f) and the density of the ZnO nanorods similarly increased. The further reduction of the seeding time to 10 min certainly causes a thinner and not uniform buffer layer (not detectable in the SEM cross section image), leading to a reduction of the CBD growth rate. Therefore, the ZnO nanorods growth (Fig. 7c and d) over high temperature (500 °C) buffer layer for short deposition time (10 min) resembles that obtained on seeds deposited at lower temperature (300 °C, Fig. 5a and b). This is the result of not uniform thickness due to less controlled MOCVD deposition conditions. ZnO nanorods, in addition, show a great size dispersion and a decreased density.

Nanorods length has also been tailored by changing the nutrient bath concentrations [26], namely, by increasing the Zn acetate and TMEDA concentrations, keeping constant the (TMEDA/Zn^{2+}) ratio. It is evident that CBD growth (on ZnO buffer layer deposited at 500 °C for 30 min) promotes the formation of ZnO nanorods which growth rates, diameters and lengths vary upon changing the nutrient bath concentration ([TMEDA] 15 mM, 25 mM and 50 mM). In particular, the nanorods aspect ratio (AR = length/diameter) increases upon increasing the concentration (Table 1) as shown in the prototypical SEM images reported in Fig. 8. This observation agrees well with a prevalent c-axis orientation vs a lateral growth. Moreover, there is an evidence that lower TMEDA concentrations (15 mM) result in nanorod arrays of greater density (Fig. 8a and b) compared to higher concentrations (50 mM) (Fig. 8c and d). It is worth noting that the higher precursor concentrations per unit area seem to promote the growth of nanorods, having a larger diameter, as a possible consequence of coalescence phenomena.

The XRD patterns (Fig. 9) agree with the crystalline nature of the nanorods with predominant c-axis orientation as the nutrient bath concentration is increased.

Finally, it has been demonstrated that, at higher concentration (50 mM), the CBD growth rate is strongly enhanced (~600 nm/h) over low temperature deposited (400 °C) seed layer (see Fig. 10a and b) compared to lower concentration (25 mM) counterpart (~200 nm/h, see Fig. 5a and b).

Photoluminescence measurements provide important information about the crystal quality of ZnO nanostructures. The optical response of ZnO nanorods obtained by combining 400 °C seed layer and faster CBD deposition conditions (TMEDA 50 mM) (Fig. 10) has been studied. Fig. 11 shows the related room-temperature photoluminescence (PL) spectra. The poorly crystalline seed layer presents a wide, weak ultraviolet band-edge emission peak centred at ~390 nm. After the CBD growth and despite the poor ZnO nanorod alignment (Fig. 10), photoluminescence measurements show a strong UV emission at 377 nm along with a weak and broad green emission around 550 nm (Fig. 11). The band-edge emission is typically related to recombination of free excitons [27], whilst the visible green emission is associated with the structural defects of oxygen vacancies [28].

The band-edge emission peak is very sharp and narrow (FWHM = 14 nm) and the large intensity ratio of UV to green PL points to the high crystal quality of ZnO nanorods, despite the low crystallinity of the seed layer. In fact, the relative high PL intensity
ratio between the UV and green emissions indicates that ZnO nanorods have low concentration of deep level defects [5,22,29,30]. It can be concluded that higher concentration of CBD bath can improve the crystal quality, growth rate and optical properties of the corresponding ZnO nanorods, despite the crystal quality of the ZnO seed layer.

4. Discussion

In this study, the effects of several different ZnO seed layers, deposited by MOCVD, on the CBD growth of homologous ZnO nanorods have been investigated. Density, size, and growth rate have been studied. The results provide an evidence of slower growth rates upon increasing the overall roughness and morphological complexity of seed layers. Meanwhile, the density of nanorods per unit area is larger as a consequence of smaller diameter values. Of course, greater morphological complexities of the seed layers involve a large number of nucleation sites that can be accessed by the ZnO precursor in the CBD solution. In this case, the total precursor (Zn\(^{2+}\)) and OH\(^{-}\) concentration at the solution-substrate interface is decreased, thus slowing down the overall growth rate. In fact, ZnO amorphous seed layers deposited by drop casting [19] have greater CBD growth rates than those deposited over the crystalline substrates. It, therefore, transpires that, at higher nucleation densities, the gradient concentration experienced by each nucleation site fall-off, thus producing shorter and thinner nanorods.

The seed layer characteristics also affect the alignment of the ZnO nanorods. Poorly crystalline and not oriented seeds induce the growth of slanted nanorods, having, in addition, greater dispersion of dimensions. As already observed, the thickness of the seed is an additional factor that impacts on the overall quality of the ZnO nanorods and on the related growth rates. In particular, greater growth rates are observed in the case of thinner seed layers [21]. In this context, MOCVD seed layers obtained at lower deposition temperatures (300 °C) or at shorter process times (10 min), are poorly uniform and therefore not suitable for high quality CBD ZnO nanorods growth.

The aspect ratio of ZnO nanorods grown in solution is governed by the relative growth rates of the polar [001] and of the non-polar [101] and [100] surfaces [5,31–33]. ZnO, in fact, exhibits partial polar characteristics, having the opposite ends of (001) plane positively (Zn\(^{2+}\)) and negatively (O\(^{-}\)) charged and characterised by high surface energy. Non-polar planes are thermodynamically more stable and, hence, the CBD growth process favours nanorods growth along the [0001] direction where the large facets are usually the non-polar planes. Nanorods are, therefore, c-axis textured to minimise the exposed surface area of the polar facets and to reduce the surface energy.

Seed layers having higher roughness might, in addition, cause nanorods coalescence effects. In fact, not enough smooth (at the nanoscale level) substrates have nucleation seeds with the (001) planes not parallel to the substrate. Growing nanorods, therefore, mismatch the c-axis direction, merge with other nanorods and larger nanostructures are produced. For this reason, ZnO nanorods grown over flake-like substrates appear extremely slanted with coalesced nanostructures and a wide size distribution.

Precursor concentrations (Zn acetate and complexing agent/base) in the nutrient bath are also critical factors to control the aspect ratio and surface density of ZnO nanorods [26]. Present data agree well with a trend [34] of increasing rates upon increasing the concentration with structures having a predominant c-axis texturing and greater aspect ratio (see Table 1).

Finally, higher bath concentration (50 mM) results in faster ZnO nanorods growth rate on less crystalline seed layers (400 °C). In particular, it has been demonstrated how growth rate increases from ~200 nm/h to ~600 nm/h upon varying the bath concentration from 25 mM to 50 mM.

Present ZnO nanostructures have also a strong UV emission and may represent important materials in optoelectronics. In fact, the optical qualities of the ZnO nanorods have been tested and good performances were found for the structures grown on low temperatures seed layer (400 °C) using a high CBD bath concentration (50 mM). It is worth noting that the UV emission peak is very sharp and has a narrow full width at half-maximum (FWHM = 14 nm). The predominance of the UV peak over the weak green band (\(\text{UV/}\text{green} = 10\)) provides a clear evidence of the high optical and crystalline quality of the ZnO neo-formations [5,22,29,30], despite their poor vertical alignment.

5. Conclusion

A two steps MOCVD-CBD approach is presented as a strategy to fabricate c-axis oriented ZnO nanorods. Effects of the ZnO buffer layer, deposited by MOCVD, on the subsequent CBD growth of ZnO nanorods have been scrutinised. The thickness and structural complexity of the ZnO buffer layer has a great impact on the nanorods growth rate and greater surface roughness slow down the CBD growth. In fact, the ZnO buffer layer acts as a nucleation template for the ZnO nanorods growth and, hence, more complex templates have more ZnO nuclei that favour a higher ZnO nanorods density. Nevertheless the corresponding growth rate appears slowed down due to an overall decrease of the Zn\(^{2+}\) and OH\(^{-}\) concentration at the substrate-CBD solution interface.

Moreover, the good crystalline grade of seed layers appears strongly related to the MOCVD deposition temperature and represents an important parameter to improve texturing of ZnO nanorods. Furthermore, the effect of nutrient bath concentration on CBD growth rate has been investigated. Lower nutrient bath concentrations are associated with slower ZnO growth rate. Upon increasing the concentration, the CBD process is faster and the global nanorods aspect ratio is increased thus supporting the preferential 1-D growth along the c-axis of the ZnO nanostructures.

Finally, it has been demonstrated that the present approach is effective to grow, even over low quality buffer layers, deposited via MOCVD at low (400 °C) process temperature, long and crystalline ZnO nanorods possessing, at room temperature, a strong ultra-violet (UV) photoluminescence edge emission at about 3.28 eV and a weak green contribution. This is the evidence of limited defect densities of the obtained ZnO nanostructures.

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